

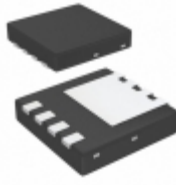
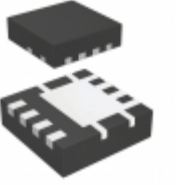
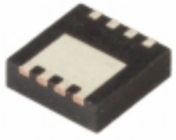
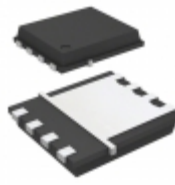
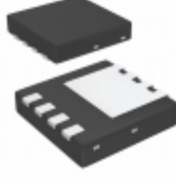
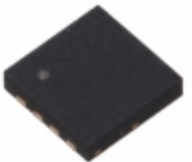
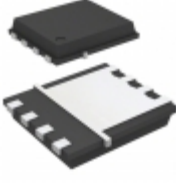
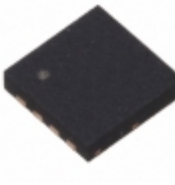
	<h2 style="color: #E67E22;">FDMC8676</h2>
	<p>Hersteller-Teilenummer: FDMC8676</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 16A POWER33</p> <hr/> <p>Datenblätter:  FDMC8676.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 3956 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMC8676
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 30V 16A POWER33
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3956 pcs Stock
Serie	PowerTrench®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-PQFN (3.3x3.3), Power33
Verlustleistung (max)	2.3W (Ta), 41W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	16A (Ta), 18A (Tc)
Rds On (Max) @ Id, Vgs	5.9 mOhm @ 14.7A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1935pF @ 15V
Verpackung	Tape & Reel (TR)












FDMC8676 ist neu im Original, Suche FDMC8676 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMC8676 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FDMC8676: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDMC8676 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 16A POWER33</p>	 <p>FDMC8854 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 15A POWER33</p>	 <p>FDMC86570L Fairchild/ON Semiconductor MOSFET N-CH 60V 56A POWER33</p>	 <p>FDMC86570LET60 Fairchild/ON Semiconductor MOSFET N-CH 60V 56A POWER33</p>
 <p>FDMC8678S AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 15A POWER33</p>	 <p>FDMC8878 Fairchild/ON Semiconductor MOSFET N-CH 30V 9.6A POWER33</p>	 <p>FDMC8678S Fairchild/ON Semiconductor MOSFET N-CH 30V 15A POWER33</p>	 <p>FDMC8854 Fairchild/ON Semiconductor MOSFET N-CH 30V 15A POWER33</p>

heiße Teile

Mehr

 FDMC86160	 FDMC86160	 FDMC8622	 FDMC8622	 FDMC86240
 FDMC86240	 FDMC86248	 FDMC86248	 FDMC86260	 FDMC86260
 FDMC86261P	 FDMC86261P	 FDMC86324	 FDMC86324	 FDMC86340
 FDMC86340	 FDMC86340ET80	 FDMC86340ET80	 FDMC8651	 FDMC8651
 FDMC86520DC	 FDMC86520DC	 FDMC86570L	 FDMC86570L	 FDMC8676
 FDMC8678S	 FDMC8678S	 FDMC8854	 FDMC8854	 FDMC8878
 FDMC8878	 FDMC8882	 FDMC8882	 FDMC8884	 FDMC8884
 FDMC89521L	 FDMC89521L	 FDME1024NZT	 FDME1024NZT	 FDME1034CZT
 FDME1034CZT	 FDME510PZT	 FDME510PZT	 FDME820NZT	 FDME820NZT
 FDME905PT	 FDME905PT	 FDME910PZT	 FDME910PZT	 FDMF3005

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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